

IN THE CLAIMS:

Claims 1, 3, 5, 18, and 19 have been amended herein. All of the pending claims 1 through 19 are presented below. This listing of claims will replace all prior versions and listings in the application. Please enter these claims as amended.

1. (Currently Amended) A drying system for a semiconductor structure comprising:  
a vessel having a top, a bottom, and at least one side, ~~said the~~ vessel including a semiconductor stage for disposing the semiconductor structure thereon;  
a DI water inlet configured to supply DI water in ~~said the~~ vessel to at least partially fill ~~said the~~ vessel to a level that would allow the semiconductor structure disposed on ~~said the~~ semiconductor stage to be submerged in ~~said the~~ DI water;  
at least one gas inlet configured to supply a gas inert to the semiconductor structure to substantially fill ~~said the~~ vessel so that ~~said the~~ gas is maintained above ~~said the~~ level of ~~said the~~ DI water, the at least one gas inlet ~~is connected~~ connected to a fail-shut valve, the at least one gas inlet comprising one of an inlet in the top of the vessel and an inlet in ~~said the~~ at least one side of the vessel;  
a plurality of liquid inlets configured to supply a liquid to the vessel so that ~~said the~~ liquid is disposed between ~~said the~~ DI water and ~~said the~~ gas, ~~said the~~ vessel configured such that ~~said the~~ semiconductor stage having the semiconductor structure disposed thereon and an upper surface of ~~said the~~ DI water move relative to each other so that the semiconductor structure is exposed through ~~said the~~ upper surface of ~~said the~~ DI water to ~~said the~~ gas to rinse and dry the semiconductor structure in ~~said vessel<sup>2</sup>~~ the vessel; and  
at least one weir located in the ~~vessel~~ vessel.

2. (Original) The system of claim 1, wherein the vessel includes a plurality of outlets therefrom.

3. (Currently Amended) The system of claim 1, further comprising:  
at least one outlet in the vessel for allowing the gas or ~~liquid~~ DI water to be removed from the  
vessel; and  
a fail-shut valve connected to the at least one outlet in the vessel.

4. (Original) The system of claim 1, further comprising at least one outlet in the  
bottom of the vessel.

5. (Currently Amended) The system of claim 1, further comprising at least one  
outlet ~~in-said~~ the at least one side of the vessel.

6. (Original) The system of claim 1, wherein the vessel comprises a plurality of  
weirs.

7. (Original) The system of claim 1, wherein the vessel includes a plurality of  
compartments therein.

8. (Original) The system of claim 1, wherein the vessel includes a plurality of  
compartments therein for allowing flow of liquid in the vessel from one compartment to an  
adjacent compartment.

9. (Original) The system of claim 7, further comprising:  
at least one outlet connected to each compartment of the plurality of compartments of the vessel.

10. (Original) The system of claim 1, further comprising a rinsing apparatus having at  
least one spray nozzle with a portion thereof located in the vessel.

11. (Original) The system of claim 1, wherein the vessel includes a shelf therein located above the bottom of the vessel.

12. (Original) The system of claim 11, wherein the shelf includes at least one aperture therein.

13. (Original) The system of claim 1, further comprising:  
a valve apparatus connected to at least one liquid inlet of the plurality of liquid inlets.

14. (Original) The system of claim 1, wherein the vessel comprises a dry etcher.

15. (Original) The system of claim 1, wherein the vessel comprises a cascade rinser.

16. (Original) The system of claim 1, wherein the vessel comprises an overflow rinser.

17. (Original) The system of claim 1, wherein the vessel comprises a Marangoni dryer.

18. (Currently Amended) The system of claim 1, wherein ~~said~~ the semiconductor stage is raisable so that ~~said~~ the semiconductor structure is drawn through ~~said~~ the upper surface of ~~said~~ the DI water to ~~said~~ the gas.

19. (Currently Amended) The system of claim 1, wherein ~~said~~ the vessel comprises at least one drain to lower ~~said~~ the upper surface of ~~said~~ the DI water to facilitate exposing ~~said~~ the semiconductor structure to ~~said~~ the gas.